

#### NCE N-Channel Enhancement Mode Power MOSFET

#### **Description**

The NCE0103M uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

•  $V_{DS} = 100V, I_{D} = 3A$ 

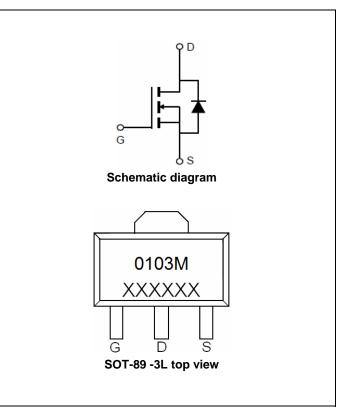
 $R_{DS(ON)}\,{<}160m\Omega\;\textcircled{0}\;V_{GS}{=}10V\quad (Typ:136m\Omega)$ 

 $R_{DS(ON)}$  <170m $\Omega$  @  $V_{GS}$ =4.5V (Typ:140m $\Omega$ )

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

#### **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
0103M	NCE0103M	SOT-89-3L	Ø180mm	12mm	1000units

Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Voltage	V <sub>GS</sub>	±12	V
Drain Current-Continuous	I <sub>D</sub>	3	Α
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	20	Α
Maximum Power Dissipation	P <sub>D</sub>	1.5	W
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	$^{\circ}\!$

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	83	°C/W
	• •00/1		

## **Electrical Characteristics (T<sub>A</sub>=25 ℃ unless otherwise noted)**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	100	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA



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# NCE0103M

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V,V <sub>DS</sub> =0V	-	-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	0.6	1.1	1.8	V	
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =3A	-	136	160	mΩ	
Drain-Source On-State Resistance		V <sub>GS</sub> =4.5V, I <sub>D</sub> =3A	-	140	170		
Forward Transconductance	<b>g</b> FS	$V_{DS}$ =5 $V$ , $I_{D}$ =3 $A$	-	5	-	S	
Dynamic Characteristics (Note4)							
Input Capacitance	C <sub>lss</sub>	\/ -50\/\/ -0\/	-	650	-	PF	
Output Capacitance	Coss	$V_{DS}$ =50V, $V_{GS}$ =0V, F=1.0MHz	-	24	-	PF	
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UIVID2	-	20	-	PF	
Switching Characteristics (Note 4)							
Turn-on Delay Time	t <sub>d(on)</sub>		-	6	-	nS	
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =50V, $R_L$ =19 $\Omega$	-	4	-	nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =3 $\Omega$	-	20	-	nS	
Turn-Off Fall Time	t <sub>f</sub>		-	4	-	nS	
Total Gate Charge	Qg	\/ F0\/   0A	-	20		nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=50V,I_{D}=3A,$	-	2.1	-	nC	
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	3.3	-	nC	
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =3A	-	-	1.2	V	
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	3	Α	

#### Notes:

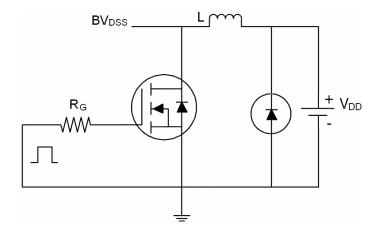
- **1.** Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to productio



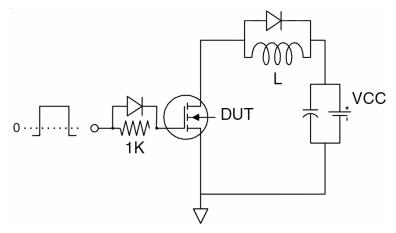
Pb-Free Product

## **Test Circuit**

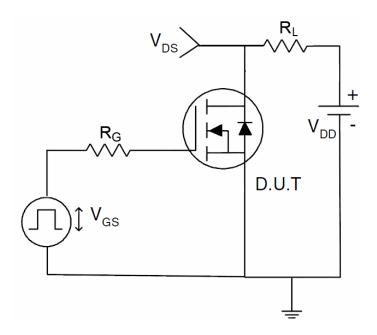
## 1) E<sub>AS</sub> test circuit



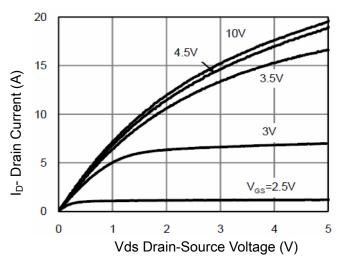
## 2) Gate charge test circuit



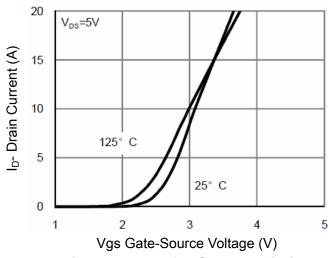
## 3) Switch Time Test Circuit



## **Typical Electrical and Thermal Characteristics (Curves)**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

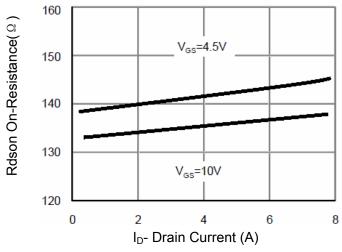


Figure 3 Rdson- Drain Current

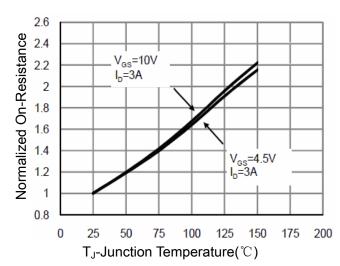


Figure 4 Rdson-JunctionTemperature

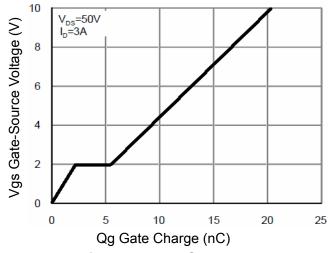


Figure 5 Gate Charge

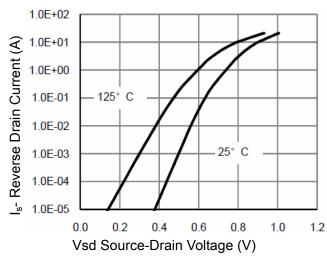
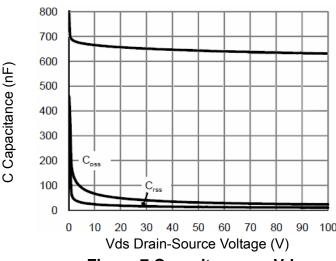


Figure 6 Source- Drain Diode Forward

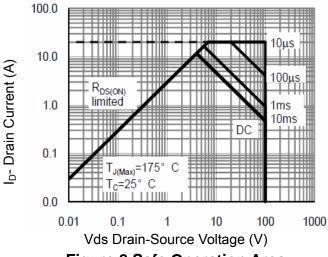


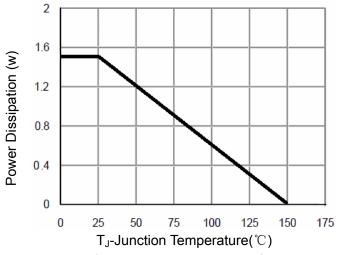
2.5 Ip- Drain Current (A) 2 1.5 1.0 0.5 0 25 50 75 125 150 0 100 175 T<sub>J</sub>-Junction Temperature(°C)

3

Figure 7 Capacitance vs Vds







**Figure 8 Safe Operation Area** 

Figure 10 Power De-rating

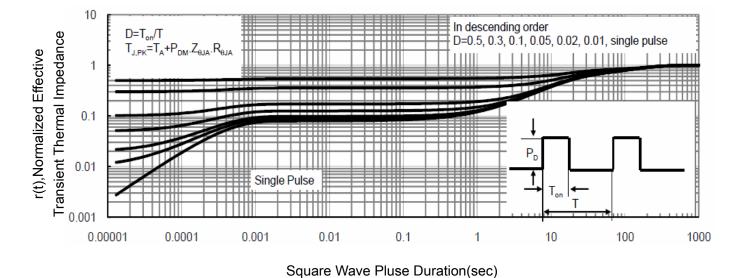
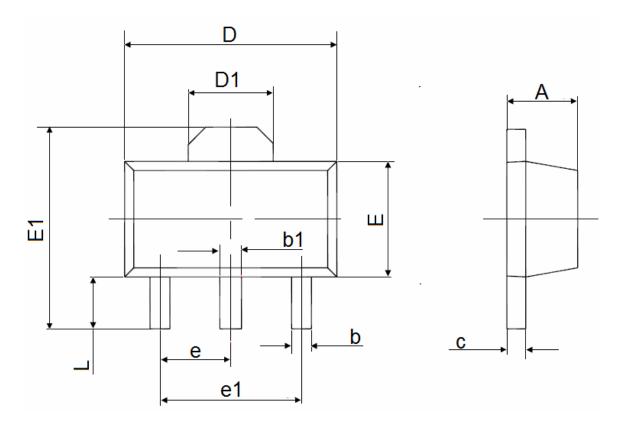


Figure 11 Normalized Maximum Transient Thermal Impedance

# **SOT-89-3L Package Information**



Cymbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	1.400	1.600	0.055	0.063	
b	0.320	0.520	0.013	0.020	
b1	0.400	0.580	0.016	0.023	
С	0.350	0.440	0.014	0.017	
D	4.400	4.600	0.173	0.181	
D1	1.550	REF.	0.061 REF.		
E	2.300	2.600	0.091	0.102	
E1	3.940	4.250	0.155	0.167	
е	1.500	TYP.	0.060 TYP.		
e1	3.000	TYP.	0.118 TYP.		
L	0.900	1.200	0.035	0.047	

#### **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$

**Pb-Free Product** 

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